

## Probing Confined Phonon Modes in Individual CdSe Nanoplatelets Using Surface-Enhanced Raman Scattering

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The phonon modes of individual ultrathin CdSe nanoplatelets are investigated using surface-enhanced Raman scattering in a tightly confined plasmonic geometry. The surface-enhanced Raman scattering spectra, taken on single nanoplatelets sandwiched between a gold nanoparticle and a gold surface, reveal a phonon doublet arising from oscillations perpendicular to and within the platelet plane. The out-of-plane mode cannot be observed with conventional Raman spectroscopy. The resulting strong electric field enhancements and the field vector reorientation within such nanometer-sized plasmonic gaps reveal otherwise hidden information deep into the Brillouin zone illuminating the vibrational properties of ultrathin materials.

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Metallic nanoparticles in close proximity support strong electromagnetic fields confined in the gap between them [1,2]. Such plasmonic nanogaps are of increasing interest due to their ability to strongly enhance optical processes such as Raman scattering in order to detect trace concentrations of substances with sensitivities down to the single molecule level [3–6]. Colloidal nanoplatelets [7–9], consisting of a thin (multi-atomic-layer) crystalline slab of inorganic material, represent an atomic system with high spatial confinement in a single dimension. Nanoplatelets have been grown from a wide variety of materials, but those made from semiconductors, which act as two-dimensional quantum wells, give particularly interesting optical properties. Their photoluminescence can be precisely tuned by varying the number of atomic layers in the slab, thus altering the spatial confinement of excitons and their resulting confinement and binding energies. Planar semiconducting nanoplatelets are thus useful to a broad range of disciplines ranging from solar cells and single-photon sources to molecular tagging and sensing. As well as exciton confinement, the phonons inside these ultrathin semiconductor structures also feel confinement effects.

Here we demonstrate that plasmonic field localization can be used to study the phonon confinement in extremely thin individual nanoplatelets consisting of a handful of atomic layers. Besides electric field enhancement, the reorientation of the electric field vector perpendicular to the surface allows access to highly confined phonon modes not visible in standard Raman spectroscopy. Despite extensive research on Raman scattering of nanocrystals [10–15], there has been little focus on the surface-enhanced Raman scattering (SERS) of colloidal quantum dots [16–18]. Until now no reports exist of SERS of individual semiconducting nanoparticles. We investigate the Raman scattering of individual CdSe nanoplatelets [7] sandwiched between a gold (Au)

nanoparticle (NP) and a planar gold surface. The nanoparticle-on-mirror geometry (NPOM) [19–21] enables highly-effective plasmonic coupling and convenient investigation of a single plasmonic junction, allowing the interrogation of single nanoplatelets. The dramatic change in the electric-field distribution in such a nanometer-sized gap and the resulting modification of traditional Raman selection rules allow us to probe phonon generation in CdSe nanoplatelets with different spatial dimensions. In this SERS configuration, we observe a highly confined longitudinal optical (LO) phonon mode perpendicular to the platelet plane, which is invisible in conventional Raman scattering. The spectral position of this out-of-plane [LO( $z$ )] phonon is in agreement with existing phonon confinement models for spherical nanocrystals [12–14,22]. This work highlights the use of SERS within plasmonic nanogaps to not only provide a dramatic field enhancement but also reveals modes that are not visible in conventional Raman scattering.

Samples for SERS were prepared as follows. Colloidal nanoplatelets were grown by wet chemistry [6]. A 70 nm thick gold film was electron-beam evaporated on a silicon wafer, and then functionalized with a monolayer of 4-aminothiophenol (ATP) by immersion in a 10 mM ethanolic solution for 24 h. These prepared surfaces, rinsed clean and dried, were then dipped in colloidal solutions of nanoplatelets in hexane for another 24 h. This gives a homogenous monolayer of platelets lying flat with a surface coverage of  $\sim 60\%$  as verified by AFM. Colloidal Au NPs with a 100 nm diameter were drop cast onto the surface, where they physisorb, and after 5 min, unbound particles were washed away. For conventional Raman scattering, colloidal platelets were dropped on a clean silicon wafer and dried. Platelets in this case form stacks [23], which are in random orientations with respect to the surface. Raman spectra were measured on a

Renishaw inVia Raman microscope at excitation wavelengths of 532 and 633 nm. The microscope was set up in backscattering configuration and a 100x objective with  $NA = 0.85$  was used for excitation and collection of scattered light. The incident light was unpolarized. The SERS spectra were collected from a single nanoparticle in the sandwich formation described above. This was ensured by a sufficiently sparse coverage of Au NPs on the surface (see the Supplemental Material [24]).

We analyze the Raman and SERS spectra taken in the NPOM geometry [Fig. 1(a)] for different CdSe platelets with three, four, and five atomic layers, which correspond to thicknesses of 1.064, 1.368, and 1.672 nm [25]. The platelets investigated have a zinc blende lattice [6], rather different from the normal wurtzite structure for spherical nanoparticles. Besides their thickness, they also differ in their lateral dimensions. The three-layer thick platelets are  $\sim 200$  nm long and  $\sim 50$  nm wide. The four-monolayer platelets are  $\sim 10 \times 10$  nm and the five-layer platelets are  $\sim 25 \times 7$  nm [Figs. 1(b)–1(d)]. Their bandgap wavelength is, however, defined only by their thickness [7] and corresponds to 460 nm for the three-layer, 510 nm for the four-layer, and 550 nm for the five-layer structures.

The SERS spectra typically show the LO mode near  $200 \text{ cm}^{-1}$  [26] and a weak signature of the first overtone  $2(\text{LO})$ . In addition to these modes, the bulk Raman spectra reveals the  $3(\text{LO})$  as well as the surface mode at  $\sim 180 \text{ cm}^{-1}$

appearing as a weak shoulder (not shown). The surface mode is strongest for the three-layer platelets and diminishes for increasing platelet thickness as a result of decreasing surface to volume ratio. A minor peak is seen near  $270 \text{ cm}^{-1}$ , which is identified as cadmium sulfide [27] and most likely stems from interaction with the thiols in the ATP. We focus discussions on the LO mode and start with observations made on the four-monolayer thick platelets with near-resonant excitation at 532 nm. The SERS in the NPOM geometry shows a strong peak of the LO phonon mode at  $200 \text{ cm}^{-1}$ , while in the bulk Raman spectrum taken on the silicon wafer this mode appears at  $206 \text{ cm}^{-1}$  [Figs. 2(a)–2(c)]. The  $200 \text{ cm}^{-1}$  SERS peak is attributed to a phonon with wave vector perpendicular to the platelet plane [ $\text{LO}(z)$ ] whose strong spatial confinement leads to a spectral shift with respect to the bulk CdSe LO phonon ( $\sim 210 \text{ cm}^{-1}$ ). The Raman peak at  $206 \text{ cm}^{-1}$  mainly originates from a phonon with wave vector directed along the platelet plane [ $\text{LO}(x)$ ], which is far less spatially confined. The selective excitation of the out-of-plane phonon in the SERS is explained by the strong vertical electric field polarization in the nanogap within the NPOM assembly, hence perpendicular to the nanoplatelet [18]. The strongly confined optical field enables coupling to the out-of-plane phonon mode. In conventional Raman scattering, the spectrum is dominated by the in-plane mode, which is present over a far larger surface area and hence has a larger interaction cross section with the incident light. This is also confirmed by the Raman selection rules. With the  $z$  direction normal to the (001) platelet face [28], the  $\text{LO}(x)$

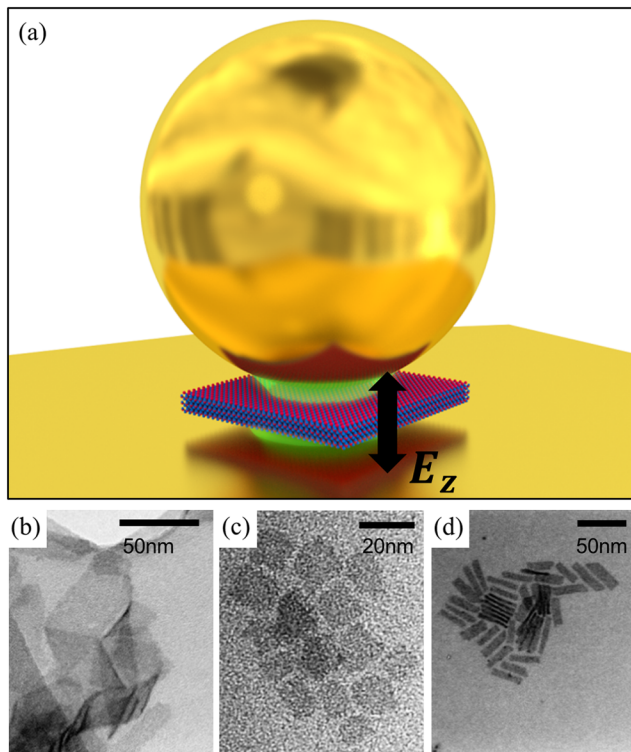


FIG. 1 (color online). (a) Individual CdSe platelet in a nanogap. (b)–(d) TEM of CdSe platelets with (b) three, (c) four, and (d) five atomic layers.

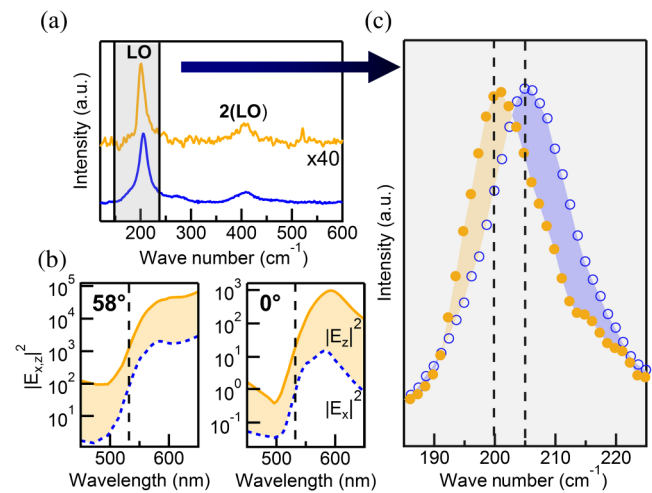


FIG. 2 (color online). (a) SERS spectrum from single NPOM geometry (top, yellow) and corresponding bulk Raman spectrum (bottom, blue) of four-layer-thick CdSe platelets (SERS trace is offset and multiplied by 40 for clarity). (b) Field components  $|E_z|^2$  (yellow, solid line) and  $|E_x|^2$  (blue, dashed line) in the nanogap. Left graph is for  $58^\circ$  incidence (maximum illumination angle for  $NA = 0.85$ ), right for normal incidence. Black dashed line indicates Raman excitation. (c) Magnified spectra of LO phonon mode for bulk Raman (blue, empty circles) and SERS (yellow, solid circles) with intensities normalized.

mode is allowed in the backscattering geometry  $z(x', x')\bar{z}$ , whereas  $LO(z)$  is forbidden (as observed away from the NPOM). Inside the nanogap the selection rules are changed because effectively the excitation geometry becomes  $x(z', z')\bar{x}$  and  $LO(z)$  becomes allowed.

To calculate the SERS enhancement factors we collect Raman scattered light from a diffraction limited spot on a monolayer of CdSe platelets on the planar gold surface and compare to that from a location containing a single gold NP on top of one of the CdSe platelets. The collected Raman scattered light for 532 nm excitation is approximately 5 times higher for the case with the Au NP, due to the creation of a localized electric field hotspot within a single platelet. Taking into account that only the plasmonic junction (whose lateral field diameter is given by  $w = \sqrt{Rd}$  for NP radius  $R$  and gap size  $d$  [29]) contributes to this enhancement while the collection area is  $1 \mu\text{m}$  in diameter, we obtain an actual SERS enhancement inside the gap of  $\sim 5 \times 10^4$ . The field in the nanogap is strongly polarized along the  $z$  axis within the range of excitation angles given by the numerical aperture, as qualitatively found by modeling the system with different angles of incidence using the boundary-element method. In Fig. 2(b), the simulated near-field components in the platelet plane ( $x$ ) and vertical to the platelet plane ( $z$ ) are shown for normal incidence ( $|E_z|^2 = 10$ ,  $|E_x|^2 = 1$  at the Raman excitation line) and the maximum angle of  $58^\circ$  ( $|E_z|^2 = 10^3$ ,  $|E_x|^2 = 10^2$ ). This tenfold larger  $|E|^2$  results in 2 orders of magnitude higher field enhancement in the  $z$  direction (as SERS scales as  $|E|^4$ ). Despite neglecting irregularities of the NP shape as well as possible chemical enhancement effects, the experimental findings are well supported.

To reveal the confinement-dependent properties of the phonon modes we compared nanoplatelets of three different thicknesses with three, four and five atomic layers. While the three-layer crystals were pumped with 532 nm analogous to the four-layer sample, we had to employ an excitation wavelength of 633 nm for the five-layer platelets to avoid the strong photoluminescence that masks the Raman peaks. While SERS of the four-layer platelets shows the out-of-plane phonon more prominently than the in-plane mode, both modes have comparable intensities for the three- and five-monolayer systems [Fig. 3(a)]. By contrast, the bulk Raman spectra contain only one peak in all three cases, identified as the in-plane mode [Fig. 3(b)]. The relatively smaller excitation of out-of-plane amplitudes on the three and five monolayers is likely because the four-layer system is excited closer to the excitonic resonance, resulting in resonant Raman scattering with more efficient coupling to the LO phonon modes. While bulk Raman scattering on arrays of such CdSe platelets showed recently [11] that spectral tuning with respect to the exciton determines which phonon modes are observed, here the geometry of the extreme plasmonic enhancement on single nanoparticle constructs is instead responsible. While the spectral mode

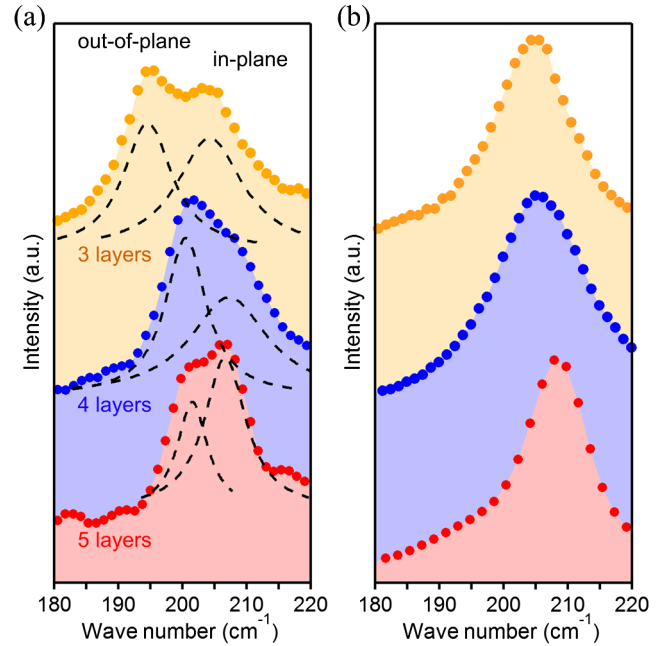


FIG. 3 (color online). (a) SERS of CdSe nanoplatelets with different thickness: three, four, and five atomic layers. (b) Conventional Raman scattering of a bulk film of the same platelets. Spectra are averaged over  $\sim$ ten spectra from different nanoparticles and offset for clarity.

positions remain highly reproducible, the intensity ratio between in-plane and out-of-plane modes fluctuates between different nanoparticle sandwiches. Nanoscale deviations of each Au NP from a spherical shape lead to a dramatic variation in the plasmonic resonance conditions for such extreme confinement, and thus the observed enhancement.

The spectral mode positions for the SERS and bulk Raman experiments are shown in Fig. 4(a). The out-of-plane  $LO(z)$  mode redshifts strongly by  $7 \text{ cm}^{-1}$  between the five- and three-layer platelets while the in-plane modes are much less sensitive to the platelet geometry. The frequencies of the in-plane mode in SERS and bulk Raman spectra do not exactly match for the four- and five-layer platelets, most likely due to additional out-of-plane contributions to the bulk Raman spectra, which induce broadening and slight line asymmetries [Fig. 4(b)].

The phonon shift is explained by two contributions. First, the negative dispersion of the LO branch away from the zone center causes a redshift with increasing phonon confinement (which accesses higher phonon wave vectors). The second contribution arises from the contraction of the crystal lattice near the surface [12,13]. In order to determine the contribution of the negative dispersion, we consider the platelets as a one-dimensional quantum well. The phonon eigenfrequencies can be expressed by [14]

$$\omega_{n,LO}^2 = \omega_{\text{bulk},LO}^2 - \beta_{LO}^2 q_n^2. \quad (1)$$

The crystal momentum of the integer  $n$ th resonance under spatial confinement with a platelet thickness  $d$  is given by



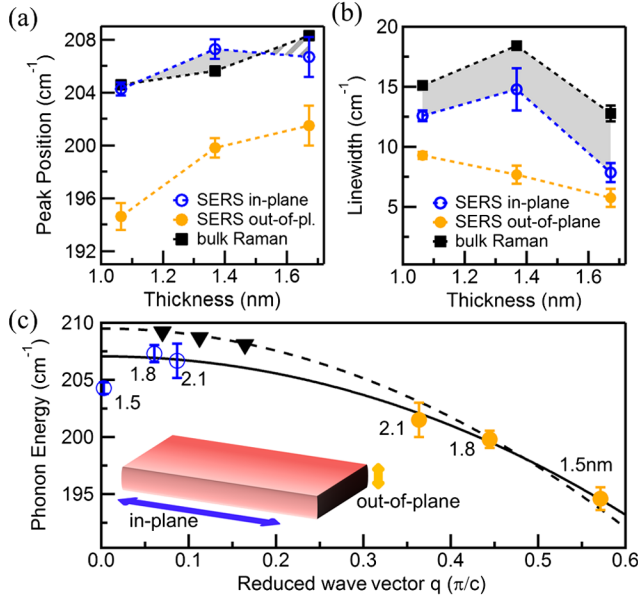


FIG. 4 (color online). (a) Peak positions and (b) linewidths (FWHM) of SERS and bulk Raman spectra. (c) Phonon energies versus reduced wave vector (in units of the lattice constant). Yellow points are the out-of-plane mode with black curve fit to Eq. (1). Blue circles show the in-plane mode. Black triangles and dashed black curve are data points and fit for spherical nanocrystals from Hwang *et al.* [13].

$$q_n = \frac{n\pi}{d}. \quad (2)$$

The parameter  $\beta_{LO}$  describes the dispersion relation of the LO branch, which is assumed to be quadratic in the long wavelength limit where the relevant lattice parameter  $c = 0.61$  nm.

Fitting the strongly confined out-of-plane modes [Fig. 4(c), yellow points] and the in-plane modes of four- and five-layer platelets (blue circles) yields  $\omega_{\text{bulk,LO}} = 207.1$  cm<sup>-1</sup> and  $\beta_{LO} = 2.27 \times 10^3$  m/s. We note that the in-plane mode of the three-layer platelets is redshifted compared to the predictions of this confinement model. As the three-layer platelets are much longer ( $\sim 200$  nm) than the other two types, geometric defects can occur such as curling and folding [Fig. 1(c)] [28], which can account for these redshifts. Previous data are only available on spherical quantum dots in the wurtzite lattice structure. Hwang and Park [13] suggest  $\beta_{LO} = 2.97 \times 10^3$  m/s although their data reach much less far out from the zone center (and hence produce fivefold smaller energy shifts, data added to Fig. 4(c) with fit dashed). For the spherical crystals, we use  $q_n = 2\mu_n/d$  [14], with  $\mu_n$  as the  $n$ th node of the  $J_1$  Bessel function, and a lattice parameter  $c = 0.70$  nm. The discrepancy between our data and the spherical crystals originates in the different lattice geometry (zinc blende) as well as a higher lattice contraction in the platelets. In our case, the phonons travel in close proximity along the crystal surface where the strain reaches a

maximum. We also note that the phonon dispersion in bulk wurtzite CdSe measured by inelastic neutron scattering [30] yields  $\beta_{LO} = 2.48 \times 10^3$  m/s, which is comparable to the measurements above, but the appropriate zinc blende structure cannot be stabilized in the bulk.

The linewidths of out-of-plane and in-plane modes exhibit different thickness dependences. The higher spatial confinement of the out-of-plane mode for decreasing platelet thickness results in a stronger phonon-phonon interaction and subsequent relaxation at the boundaries of the platelets. This leads to a near doubling of the FWHM linewidth from 5.7 to 9.2 cm<sup>-1</sup> in the three- to five-layer platelets [Fig. 4(b)]. The linewidth of the in-plane phonons follows a different dependence but is largest on the four-monolayer platelets, probably because of the different near-resonant excitation condition. These changes in linewidth for different phonon confinement track the increasingly large phonon wave vectors involved [Fig. 4(c)].

In conclusion, we demonstrate the capability of studying SERS on single ultrathin semiconductor platelets of different numbers of monolayers. Using the extreme plasmonic confinement in the nanoparticle-on-mirror NPOM geometry accesses for the first time the SERS of individual semiconductor nanostructures. The measurements reveal an energy splitting between in-plane and out-of-plane LO phonons in these CdSe nanoplatelets, not observable in conventional Raman spectroscopy. The spectral position of the out-of-plane component is highly sensitive to the thickness of the platelet in agreement with a phonon-confinement model. The concept of spatially confined phonons can thus be used for noninvasive thickness probing of nanometer-thin semiconductor films with angstrom-level precision. This is of great interest to a broad range of nanofabrication technologies where accurate film thickness control is required. This also opens the potential to excite and track local phonon interactions within and in neighboring nanostructures. Finally, the extreme plasmonic confinement and ultrathin layers access phonon wave vectors deeply into the Brillouin zone, allowing new probes of phonon coupling and decay. A wide range of ultrathin semiconductors can be utilized, for instance MoS<sub>2</sub>, WSe<sub>2</sub>, as well as many others, which opens up exciting prospects for plasmon-phonon coupling at the nanoscale.

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